1 W BTL MONO AUDIO AMPLIFIER

GENERAL DESCRIPTION

The TDA7052 is a mono output amplifier in a 8-lead dual-in-line (DIL) plastic package. The device is designed for battery-fed portable audio applications.

Features:

- No external components
- No switch-on or switch-off clicks
- Good overall stability
- Low power consumption
- No external heatsink required
- Short-circuit proof

QUICK REFERENCE DATA

parameter	conditions	symbol	min.	typ.	max.	unit
Supply voltage range		V_P	3	6	18	V
Total quiescent current	$R_L = \infty$	I_{tot}	–	4	8	mA
Voltage gain		G_v	38	39	40	dB
Output power	THD = 10%; 8 Ω	P_o	–	1,2	–	W
Total harmonic distortion	P_o = 0,1 W	THD	–	0,2	1,0	%

PACKAGE OUTLINE

8-lead DIL; plastic (SOT97).

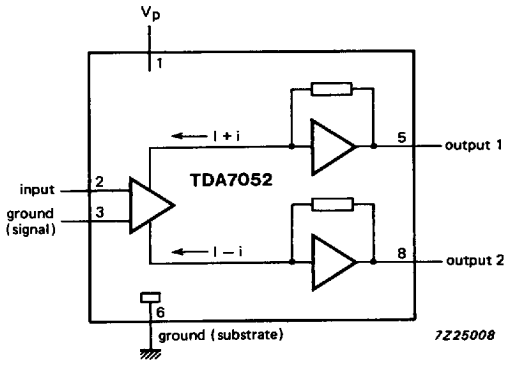

Fig. 1 Block diagram.

PINNING

1	V_P	supply voltage	5	OUT1	output 1
2	IN	input	6	GND2	ground (substrate)
3	GND1	ground (signal)	7	n.c.	not connected
4	n.c.	not connected	8	OUT2	output 2

FUNCTIONAL DESCRIPTION

The TDA7052 is a mono output amplifier designed for battery-fed portable audio applications, such as tape recorders and radios.
The gain is fixed internally at 40 dB. A large number of tape recorders and radios are still designed for mono sound, plus a space-saving trend by reduction of the number of battery cells. This means a decrease in supply voltage which results in an reduction of output power. To compensate for this reduction, the TDA7052 uses the Bridge-Tied-Load principle (BTL) which can deliver an output power of 1,2 W (THD = 10%) into an 8 Ω load with a power supply of 6 V. The load can be short-circuited at each signal excursion.

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

parameter	symbol	min.	max.	unit
Supply voltage	V_P	–	18	V
Non-repetitive peak output current	I_{OSM}	–	1,5	A
Total power dissipation	P_{tot}	see Fig. 2		
Crystal temperature	T_c	–	150	°C
Storage temperature range	T_{stg}	−55	+ 150	°C

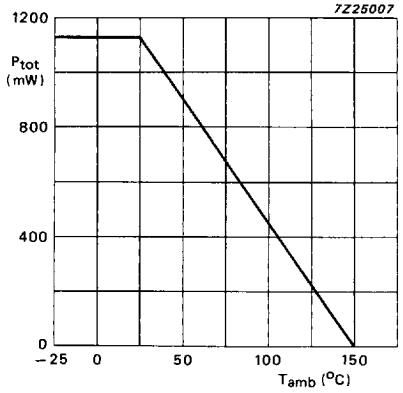

Fig. 2 Power derating curve.

POWER DISSIPATION

Assume V_P = 6 V; R_L = 8 Ω; T_{amb} = 50 °C maximum.
The maximum sinewave dissipation is 0,9 W.

$$R_{th\ j\text{-}a} = \frac{150 - 50}{0,9} \approx 110\ K/W.$$

Where $R_{th\ j\text{-}a}$ of the package is 110 K/W, so no external heatsink is required.

CHARACTERISTICS

V_P = 6 V; R_L = 8 Ω; f = 1 kHz; T_{amb} = 25 °C; unless otherwise specified.

parameter	conditions	symbol	min.	typ.	max.	unit
Supply						
Supply voltage range		V_P	3	6	18	V
Total quiescent current	$R_L = \infty$	I_{tot}	–	4	8	mA
Voltage gain		G_v	38	39	40	dB
Output power	THD = 10%	P_o	–	1,2	–	W
Noise output voltage (RMS value)						
	note 1	$V_{no(rms)}$	–	150	300	μV
	note 2	$V_{no(rms)}$	–	60	–	μV
Frequency response		f_r	–	20 Hz to 20 kHz	–	Hz
Supply voltage ripple rejection	note 3	SVRR	40	50	–	dB
DC output offset voltage pin 5 to 8	R_S = 5 kΩ	$\Delta V_{5\text{-}8}$	–	–	100	mV
Total harmonic distortion	P_o = 0,1 W	THD	–	0,2	1,0	%
Input impedance		$\|Z_I\|$	–	100	–	kΩ
Input bias current		I_{bias}	–	100	300	nA

Notes to the characteristics

1. The unweighted RMS noise output voltage is measured at a bandwidth of 60 Hz to 15 kHz with a source impedance (R_S) of 5 kΩ.
2. The RMS noise output voltage is measured at a bandwidth of 5 kHz with a source impedance of 0 Ω and a frequency of 500 kHz. With a practical load (R = 8 Ω; L = 200 μH) the noise output current is only 100 nA.
3. Ripple rejection is measured at the output with a source impedance of 0 Ω and a frequency between 100 Hz and 10 kHz. The ripple voltage = 200 mV (RMS value) is applied to the positive supply rail.

APPLICATION INFORMATION

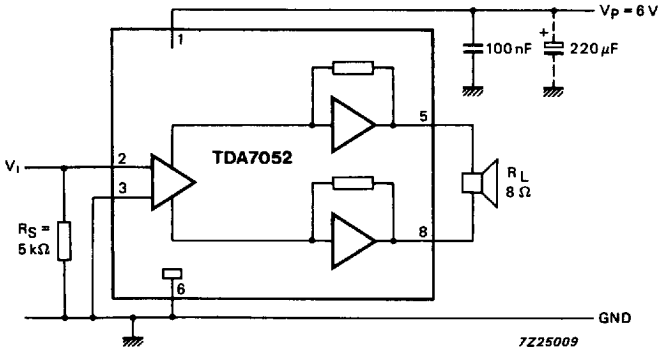

Fig. 3 Application diagram.